







100V PNP MEDIUM POWER TRANSISTOR PowerDI[®]5

Features

- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 3.2W
- V_{CEO} = -100V
- $I_C = -5A$; $I_{CM} = -10A$
- Low Saturation voltage
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Applications

SLIC DC-DC Converter

Mechanical Data

- Case: PowerDI[®]5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208 [®]
- Weight: 0.093 grams (approximate)



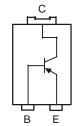




Bottom View



Device Schematic



Pin-out diagram

Ordering Information (Note 3)

Part Number	Case	Packaging
DXT2013P5-13	PowerDI [®] 5	5000/Tape & Reel

Notes:

- 1. No purposefully added lead. Halogen and Antimony Free.
- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
- 3. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



DXT2013 = Product Type Marking Code
DII = Manufacturers' Code Marking
K = Factory Designator
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 09 for 2009)
WW = Week code (01 to 53)





Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-140	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-5	A
Peak Pulse Current	I _{CM}	-10	А

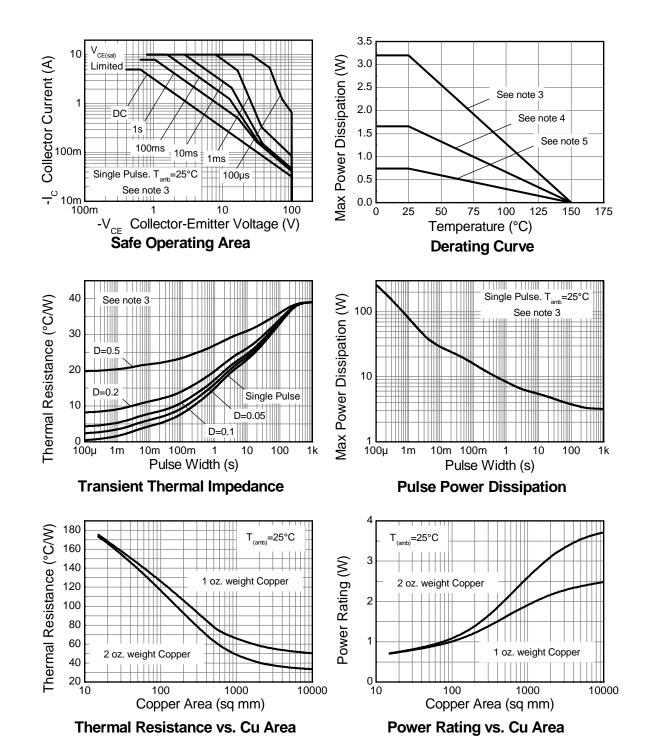
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ T _A = 25°C (Note 4)	P_{D}	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 4) @T _A = 25°C	$R_{ heta JA}$	39	°C/W
Power Dissipation @ T _A = 25°C (Note 5)	P _D	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 5) @T _A = 25°C	$R_{ heta JA}$	75	°C/W
Power Dissipation @ T _A = 25°C (Note 6)	P_{D}	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 6) @T _A = 25°C	$R_{ heta JA}$	169	°C/W
Thermal Resistance, Junction to Collector Terminal	$R_{ heta JT}$	5.6	°C/W
Operating and Storage Temperature Range	T_J , T_{STG}	-55 to +150	°C

Notes:

- Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 50mm x 50mm.
 Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 25mm x 25mm.
 Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.









Electrical Characteristics @TA = 25°C unless otherwise specified

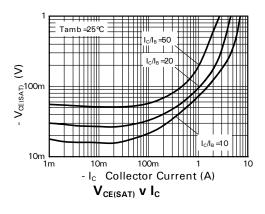
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-140	-160	_	٧	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 7)	V _{(BR)CEO}	-100	-115	_	٧	$I_C = -10 \text{mA}$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-7.0	-8.1	_	٧	$I_E = -100 \mu A$
ector Cutoff Current		_	<1	-20	nA	V _{CB} = -100V
Collector Cutoff Current	Ісво		_	-0.5	μΑ	V _{CB} = -100V, T _{amb} = 100 °C
lector Cutoff Current	I _{CER}		<1	-20	nA	V _{CB} = -100V
Collector Cutoff Current	R≤1kΩ		_	-0.5	μΑ	V _{CB} = -100V, T _{amb} = 100 °C
Emitter Cutoff Current	I _{EBO}	_	<1	-10	nA	$V_{EB} = -6V$
		_	-20	-30		$I_C = -0.1A$, $I_B = -10mA$
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}		-70	-90	mV	$I_C = -1A$, $I_B = -100mA$
Concetor Emitter Cataration Voltage (Note 1)	V CE(sat)		-120	-150		$I_C = -2A$, $I_B = -200mA$
			-240	-340		$I_C = -4A$, $I_B = -400mA$
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	_	-985	-1100	mV	$I_C = -4A$, $I_B = -400mA$
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(on)}	_	-920	-1050	mV	$V_{CE} = -4V, I_{C} = -2A$
	h _{FE}	100	250	_		$I_C = -10 \text{mA}, V_{CE} = -1 \text{V}$
C Current Gain (Note 7)		100	200	300		$I_C = -1A$, $V_{CE} = -1V$
		25	50	_	_	$I_C = -3A$, $V_{CE} = -1V$
		15 —	30	_		$I_C = -4A$, $V_{CE} = -1V$
			5	_		$I_C = -10A$, $V_{CE} = -1V$
Transition Frequency	f⊤		125	_	MHz	$I_C = -100 \text{mA}, V_{CE} = -10 \text{V},$
· ·			_			f = 50MHz
Output Capacitance	C_{obo}	_	42	_	pF	$V_{CB} = -10V$, $f = 1MHz$
Switching Times	t _{on}	_	42	_	ns	$I_C = -1A$, $V_{CC} = -10V$,
Ownering Fillios	t _{off}	_	540	_	ns	$I_{B1} = I_{B2} = -100 \text{mA}$

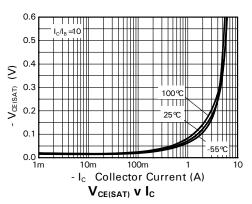
Notes: 7. Pulse Test: Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2.0\%$.

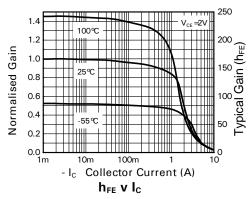


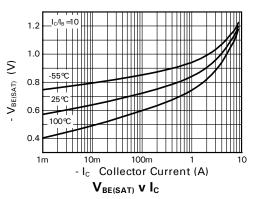


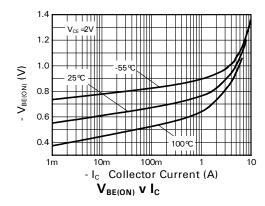
Typical Characteristic





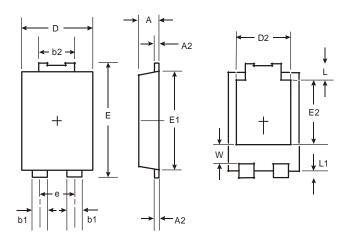






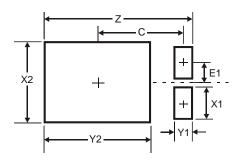


Package Outline Dimensions



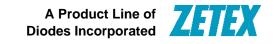
PowerDI [®] 5					
Dim	Dim Min				
Α	1.05	1.15			
A2	0.33	0.43			
b1	b1 0.80				
b2	1.70 1.8				
D	D 3.90 4.0				
D2	3.054 Typ				
Е	6.40	6.60			
е	1.84	Тур			
E1	5.30	5.45			
E2	3.549 Typ				
L	L 0.75 0.95				
L1	0.50	0.65			
W	1.10	1.41			
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
С	3.87
F1	0.0





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